

JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-23 Plastic-Encapsulate MOSFETS

CJ2302S N-Channel 20-V(D-S) MOSFET

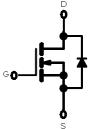
FEATURE

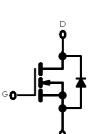
TrenchFET Power MOSFET

APPLICATIONS

- Load Switch for Portable Devices
- DC/DC Converter

MARKING: S2U





SOT-23

2. SOURCE 3. DRAIN

Maximum ratings (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit	
Drain-Source Voltage	V_{DS}	20	- V	
Gate-Source Voltage	V_{GS}	±8		
Continuous Drain Current (T _J =150°C)	I _D	2.1		
Pulsed Drain Current	I _{DM}	10	А	
Continuous Source-Drain Current(Diode Conduction)	Is	0.6		
Power Dissipation	P_D	0.35	W	
Thermal Resistance from Junction to Ambient (t≤5s)	$R_{\theta JA}$	357	°C/W	
Operating Junction	TJ	150	°C	
Storage Temperature	T _{STG}	-55 ~+150		

Electrical characteristics (T_a =25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Тур	Max	Units			
Static									
Drain-source breakdown voltage	V _{(BR)DSS}	V _G S = 0V, I _D =10μA	20			V			
Gate-threshold voltage	VGS(th)	V _{DS} =V _{GS} , I _D =50µA	0.65	0.95	1.2				
Gate-body leakage	I _{GSS}	V _{DS} =0V, V _{GS} =±8V			±100	nA			
Zero gate voltage drain current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	μΑ			
Drain-source on-resistance ^a	Fra e ()	V _{GS} =4.5V, I _D =3.6A		0.045	0.060	Ω			
	fDS(on)	Vgs =2.5V, ID =3.1A		0.070	0.115	77			
Forward transconductance ^a	G fs	V _{DS} =5V, I _D =3.6A		8		S			
Diode forward voltage	V _{SD}	I _S =0.94A,V _{GS} =0V		0.76	1.2	V			
Dynamic			•	•		•			
Total gate charge	Qg			4.0	10	nC			
Gate-source charge	Q _{gs}	V _{DS} =10V,V _{GS} =4.5V,I _D =3.6A		0.65					
Gate-drain charge	Q_{gd}			1.5					
Input capacitance	C _{iss}			300		pF			
Output capacitance	Coss	V _{DS} =10V,V _{GS} =0V,f=1MHz		120					
Reverse transfer capacitance	C _{rss}			80					
Switching			•						
Turn-on delay time	t _{d(on)}			7	15	ns ns			
Rise time	tr	V _{DD} =10V,		55	80				
Turn-off delay time	t _{d(off)}	R _L =5.5Ω, I _D ≈3.6A, V _{GEN} =4.5V,Rg=6Ω		16	60				
Fall time	t f	VGEN-4.5V,NY-012		10	25				

Notes:

a. Pulse Test : Pulse width≤300µs, duty cycle ≤2%.

Typical Characteristics

CJ2302S

